

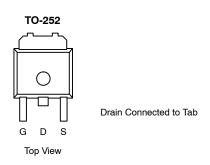
## APM2505NU-VB Datasheet

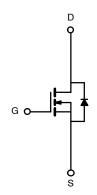
# N-Channel 20-V (D-S)175 $^{\circ}$ C MOSFET

PRODUCT SUMMARY						
V <sub>DS</sub> (V)	$r_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A) <sup>a</sup>				
20	0.0045 @ V <sub>GS</sub> = 4.5 V	100				
	0.006 @ V <sub>GS</sub> = 2.5 V	90				

#### **FEATURES**

- TrenchFET® Power MOSFET
- 175°C Maximum Junction Temperature
- 100% R<sub>g</sub> Tested





N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ unless otherwise noted)							
Parameter		Symbol	Limit	Unit			
Drain-Source Voltage	V <sub>DS</sub>	20	.,				
Gate-Source Voltage		V <sub>GS</sub>	±15				
0.11. 0.10	T <sub>C</sub> = 25°C		100				
Continuous Drain Current <sup>a</sup>	T <sub>C</sub> = 100°C	- I <sub>D</sub> -	80				
Pulsed Drain Current		I <sub>DM</sub>	200	A			
Continuous Source Current (Diode Conduction) <sup>a</sup>		Is	65				
	T <sub>C</sub> = 25°C	_	71				
Maximum Power Dissipation	T <sub>A</sub> = 25°C	P <sub>D</sub>	8.3 <sup>b, c</sup>	W			
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 175	°C			

THERMAL RESISTANCE RATINGS								
Parameter	Symbol	Typical	Maximum	Unit				
	t ≤ 10 sec.		15	18	°C/W			
Maximum Junction-to-Ambient <sup>b</sup>	Steady State	R <sub>thJA</sub>	40	50				
Maximum Junction-to-Case	R <sub>thJC</sub>	1.75	2.1					

### Notes

- a. Package Limited
- b. Surface Mounted on 1" x 1" FR4 Board
- $c. \quad t \leq 10 \ \text{sec}$

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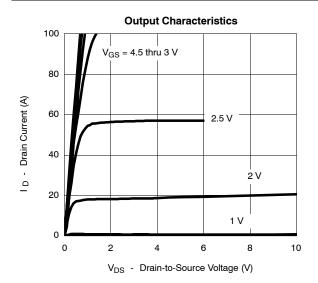
Parameter	Symbol	Test Condition	Min	Typ <sup>a</sup>	Max	Unit	
Static	<b>.</b>		1	ı			
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS}$ = 0 V, $I_D$ = 250 $\mu A$	20			.,	
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.5		1.5	V	
Gate-Body Leakage	I <sub>GSS</sub>	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ±12 V			±100	nA	
	_	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V			1	μΑ	
Zero Gate Voltage Drain Current	DSS	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 125°C			50		
On-State Drain Current <sup>b</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	100			Α	
		$V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$		0.0045	I		
Drain-Source On-State Resistanceb	r <sub>DS(on)</sub>	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 20 A, T <sub>J</sub> = 125°C		0.0055		Ω	
	\ /	$V_{GS} = 2.5 \text{ V}, I_D = 20 \text{ A}$		0.006		1	
Forward Transconductanceb	9 <sub>fs</sub>	$V_{DS} = 5 \text{ V}, I_{D} = 40 \text{ A}$	20			S	
Dynamic <sup>a</sup>			•				
Input Capacitance	C <sub>iss</sub>			3660			
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 \text{ V}, V_{DS} = 20 \text{ V}, f = 1 \text{ MHz}$		730		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			375			
Total Gate Charge <sup>c</sup>	Qg			26	35	nC	
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS}$ = 10 V, $V_{GS}$ = 4.5 V, $I_{D}$ = 40 A		5			
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			7			
Gate Resistance	R <sub>g</sub>		1		3.7	Ω	
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			20	35		
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD}$ = 10 V, $R_L$ = 0.25 $\Omega$		120	190		
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	$V_{DD}$ = 10 V, $R_L$ = 0.25 $\Omega$ $I_D \cong$ 40 A, $V_{GEN}$ = 4.5 V, $R_G$ = 2.5 $\Omega$		45	70	ns	
Fall Time <sup>c</sup>	t <sub>f</sub>			20	35		
Source-Drain Diode Ratings an	d Characteristi	c (T <sub>C</sub> = 25°C)					
Pulsed Current	I <sub>SM</sub>				100	Α	
Diode Forward Voltage <sup>b</sup>	V <sub>SD</sub>	I <sub>F</sub> = 100 A, V <sub>GS</sub> = 0 V		1.2	1.5	V	
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 40 A, di/dt = 100 A/μs		35	70	ns	

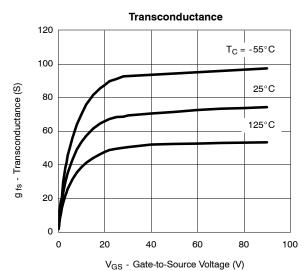
- Notes a. Guaranteed by design, not subject to production testing. b. Pulse test; pulse width  $\leq 300~\mu s$ , duty cycle  $\leq 2\%.$  c. Independent of operating temperature.

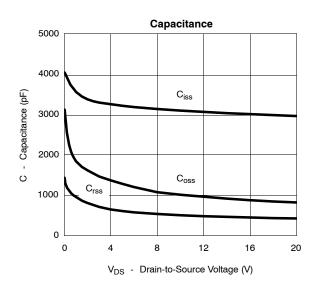
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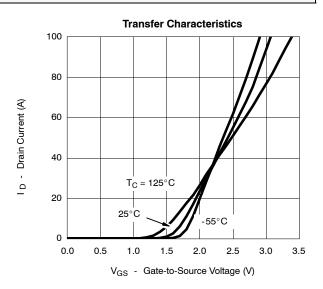


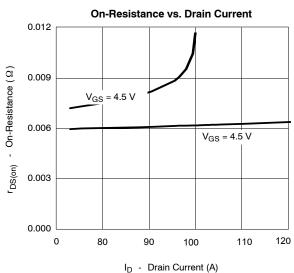
### TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

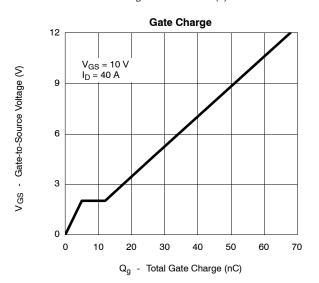






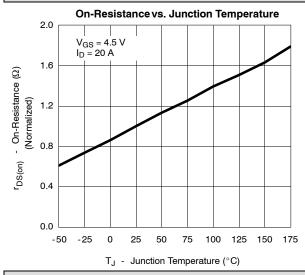


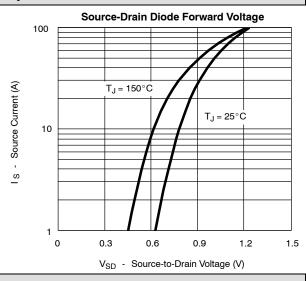




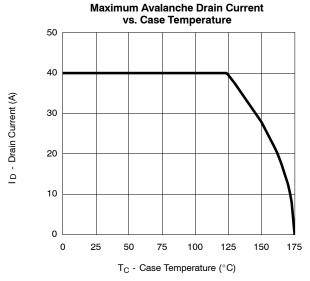


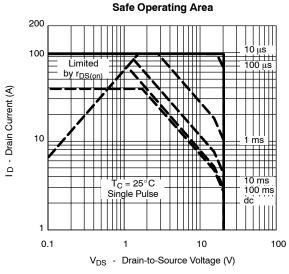
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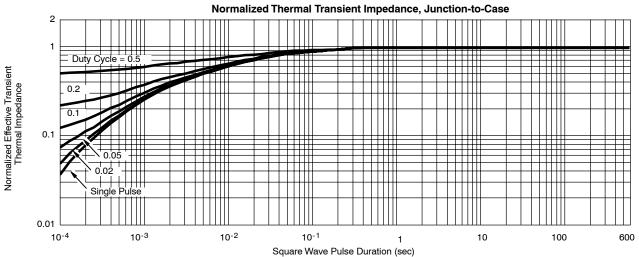




#### **THERMAL RATINGS**



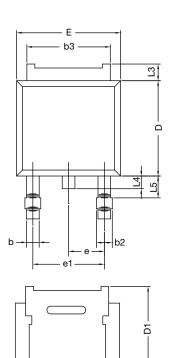


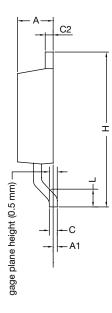


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# **TO-252AA CASE OUTLINE**





	MILLIN	METERS	INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
А	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	5.21	-	0.205	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	ı	0.170	i	
Н	9.40	10.41	0.370	0.410	
е	2.28	BSC	0.090 BSC		
e1	4.56	BSC	0.180 BSC		
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	
ECN: X12-0247-Rev. M, 24-Dec-12 DWG: 5347					

### Note

• Dimension L3 is for reference only.

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